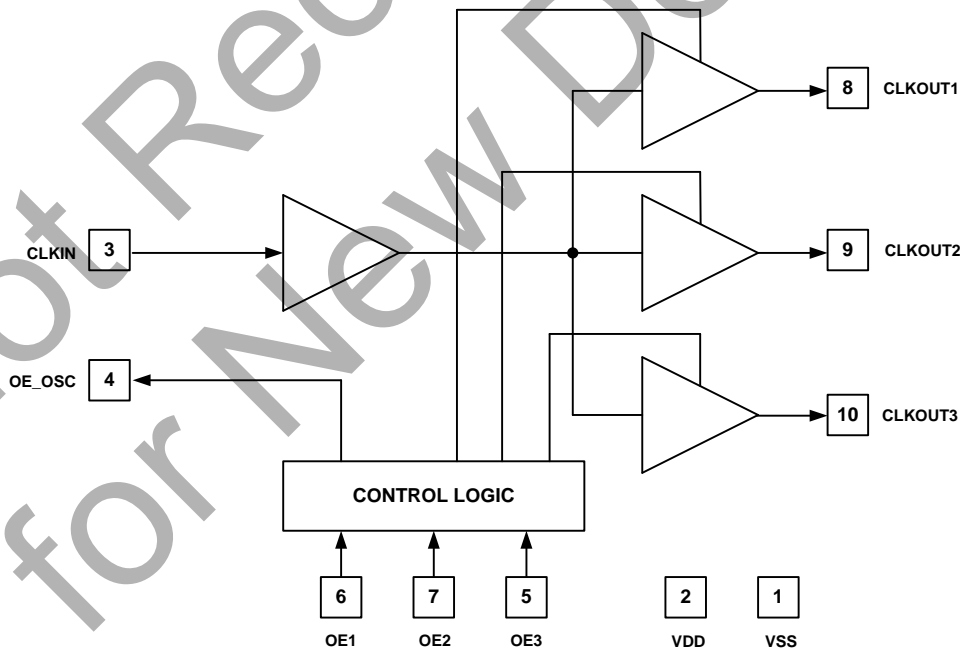


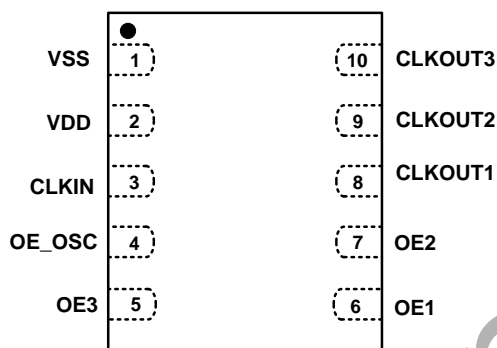
3-Channel Clock Distribution Buffer

Key Features	Description
<ul style="list-style-type: none"> • Low current consumption - 2.7mA-typ (VDD=1.8V and CL=0) • 1.7V to 3.65V power supply operation • 10MHz to 52MHz CLKIN • Supports LVCMOS and clipped sine wave inputs • Supports 3 single-ended LVCMOS square wave outputs • OE1/2/3 functions for each CLKOUT1/2/3 outputs • OE_OSC control pin to enable external TCXO/XO • Ultra-Low phase noise • Ultra low standby current • 10-pin TDFN package (1.4x2.0x0.75 mm) • Industrial -40 °C to 85 °C temperature range 	<p>The SL18860DC product is a high performance 3 output clock distribution buffer and provides 3 outputs from a single input clock by using SLI proprietary low phase noise and low power dissipation circuit design.</p> <p>The SL18860DC can be used in baseband mobile RF applications including WLAN, Bluetooth and DVB-H as an input clock reference. The product designed to isolate each device driven by their clock outputs to minimize interference between these devices.</p> <p>Each of the clock buffer outputs can be individually disabled by using OE1/2/3 control pins to reduce the power consumption if the connected device does not need the clock. The device operates from single power supply from 1.7V to 3.65V and from -40 °C to 85 °C.</p>
<p>Application</p> <ul style="list-style-type: none"> • Smart Mobile Handsets • Multi-mode RF Clock Distribution • Baseband Peripheral Clock Distribution 	<p>Benefits</p> <ul style="list-style-type: none"> • Fast Time-to-market • Cost Reduction • Low Power Dissipation • Low Phase Noise

Block Diagram



Pin Configuration



10-Pin TDFN Package Pinout

Pin Description

Pin Number	Pin Name	Pin Type	Pin Description
1	VSS	Power	Power supply ground.
2	VDD	Power	2.25 to 3.65V or 1.8V +/-5% positive power supply
3	CLKIN	Input	External clock input pin. VSS to VDD CMOS level.
4	OE_osc	Output	Crystal oscillator enable pin. If OE1=OE2=OE3=0 then OE_osc=0. OE_osc=1 for all the other OE1/2/3 logic states.
5	OE3	Input	Output enable pin for CLKOUT3. The input has 150kΩ-typ on-chip pull-down resistor.
6	OE1	Input	Output enable pin for CLKOUT1. The input has 150kΩ-typ on-chip pull-down resistor.
7	OE2	Input	Output enable pin for CLKOUT2. The input has 150kΩ-typ on-chip pull-down resistor.
8	CLKOUT1	Output	Clock output-1. Clock frequency is the same as CLKIN.
9	CLKOUT2	Output	Clock output-2. Clock frequency is the same as CLKIN.
10	CLKOUT3	Output	Clock output-3. Clock frequency is the same as CLKIN.

OE1 (Input)	OE2 (Input)	OE3 (Input)	OE_osc (Output)	CLKOUT1	CLKOUT2	CLKOUT3
0	0	0	0	Hi-Z	Hi-Z	Hi-Z
1	0	0	1	CLOCK	Hi-Z	Hi-Z
1	1	0	1	CLOCK	CLOCK	Hi-Z
...
1	1	1	1	CLOCK	CLOCK	CLOCK

Table 1. Truth Table for OE1/2/3, OE_osc and CLKOUT1/2/3

Absolute Maximum Ratings

Description	Condition	Min	Max	Unit
Supply voltage, VDD (Absolute)		-0.5	4.6	V
Supply voltage, VDD (Operation)		1.70	3.65	V
All Inputs and Outputs		-0.5	VDD+0.5	V
Ambient Operating Temperature	In operation, C-Grade	-40	85	°C
Storage Temperature	No power is applied	-65	150	°C
Junction Temperature	In operation, power is applied	-	125	°C
Soldering Temperature		-	260	°C
ESD Rating (Human Body Model)	JEDEC22-A114D	-4,000	4,000	V
ESD Rating (Charge Device Model)	JEDEC22-C101C	-1,500	1,500	V
ESD Rating (Machine Model)	JEDEC22-A115D	-200	200	V

DC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 1.8V+/- 5% and Operation Temperature Range -40 to +85°C

Description	Symbol	Condition	Min	Typ	Max	Unit
Operating Voltage	VDD	Operation range, 1.8V+/-5%	1.70	1.80	1.90	V
Operating Temperature	TA	I-Grade	-40	25	85	°C
Input Low Voltage	VIL	CMOS Level, Pins 3,5, 6 and 7	VSS	-	0.3VDD	V
Input High Voltage	VIH	CMOS Level, Pins 3,5, 6 and 7	0.7VDD	-	VDD	V
Output High Voltage	VOH	IOH=-4mA, Pins 4, 8, 9 and 10	VDD-0.4	-	-	V
Output Low Voltage	VOL	IOL=-4mA, Pins 4, 8, 9 and 10	-	-	0.4	V
Input Leakage Current	ILH	VIN=VDD, Pins 5, 6 and 7	-25	-	25	µA
Input Leakage Current	ILL	VIN=GND, Pins 5, 6 and 7	-10	-	10	µA
Pull-Down Resistor	RPD	Pins 5, 6 and 7	100	150	250	kΩ
Operating Supply Current	IDD1	CLKIN=26MHz, OE1=OE2=OE3=1	-	2.7	-	mA
Operating Supply Current	IDD2	OE1=OE2=OE3=0 CLKIN=Low or High	-	-	1.0	µA
Input Capacitance	CIN	Pins 5, 6 and 7	-	3	5	pF
Load Capacitance	CL	CLKOUT1/2/3, Pins 8, 9 and 10	-	10	20	pF

AC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 1.8V+/- 5% and Operation Temperature Range -40 to +85°C

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Input Clock Range	CLKIN	External Clock, CMOS square wave	10	26.000	52	MHz
Output Clock Range	CLKOUT	External Clock, CMOS square wave CLKOUT1/2/3	10	26.000	52	MHz
Input Clock Voltage Swing Level	VINpp	VDD=1.8V	0.72	1	-	Vpp
Input Duty Cycle	DCIN	CLKIN, Pin 3	30	50	70	%
Output Clock Rise Time	tr	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	2.0	4.00	ns
Output Clock Fall Time	tf	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	2.0	4.00	ns
Additive Phase Noise	APN-1	CLKIN=26MHz and 1 kHz offset CLKOUT1/2/3	-	-140	-	dBc/Hz
Additive Phase Noise	APN-2	CLKIN=26MHz and 10 kHz offset CLKOUT1/2/3	-	-150	-	dBc/Hz
Additive Phase Noise	APN-3	CLKIN=26MHz and 100 kHz offset CLKOUT1/2/3	-	-159	-	dBc/Hz
Power-up Time	tPU	Time duration until CLKOUT1/2/3 frequency reaches valid frequency after power supply reaches 0.9xVDD value	-	100	200	Ns
Output Enable Time	tOE1	Time from OE raising edge to active at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Disable Time	tOD	Time from OE falling edge to Hi-Z at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Enable Time	tOE2	Active recovery time from standby (CLKIN=0 or 1) to active at outputs CLKOUT1/2/3	-	100	-	Ns

DC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 2.5V+/- 10% and Operation Temperature Range -40 to +85°C

Description	Symbol	Condition	Min	Typ	Max	Unit
Operating Voltage	VDD	Operation range, 2.5V+/-10%	2.25	2.50	2.75	V
Operating Temperature	TA	I-Grade	-40	25	85	°C
Input Low Voltage	VIL	CMOS Level, Pins 3,5, 6 and 7	VSS	-	0.3VDD	V
Input High Voltage	VIH	CMOS Level, Pins 3,5, 6 and 7	0.7VDD	-	VDD	V
Output High Voltage	VOH	IOH=-4mA , Pins 4, 8, 9 and 10	VDD-0.4	-	-	V
Output Low Voltage	VOL	IOL=-4mA, Pins 4, 8, 9 and 10	-	-	0.4	V
Input Leakage Current	ILH	VIN=VDD, Pins 5, 6 and 7	-30	-	30	µA
Input Leakage Current	ILL	VIN=GND, Pins 5, 6 and 7	-15	-	15	µA
Pull-Down Resistor	RPD	Pins 5, 6 and 7	100	150	250	kΩ
Operating Supply Current	IDD1	CLKIN=26MHz, OE1=OE2=OE3=1	-	3.0	-	mA
Operating Supply Current	IDD2	OE1=OE2=OE3=0 CLKIN=Low or High	-	-	1.5	µA
Input Capacitance	CIN	Pins 5, 6 and 7	-	3	5	pF
Load Capacitance	CL	CLKOUT1/2/3, Pins 8, 9 and 10	-	10	20	pF

AC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 2.5V+/- 10% and Operation Temperature Range -40 to +85°C

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Input Clock Range	CLKIN	External Clock, CMOS square wave	10	26.000	52	MHz
Output Clock Range	CLKOUT	External Clock, CMOS square wave CLKOUT1/2/3	10	26.000	52	MHz
Input Clock Voltage Swing Level	VINpp	VDD=2.5V, connect to CLKIN directly	1.0	1.2	-	V
		VDD=2.5V, connect to CLKIN through AC coupling and bias circuit	0.6	-	-	V
Input Duty Cycle	DCIN	CLKIN, Pin 3	30	50	70	%
Output Clock Rise Time	tr	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	2.0	4.00	ns
Output Clock Fall Time	tf	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	2.0	4.00	ns
Additive Phase Noise	APN-1	CLKIN=26MHz and 1 kHz offset CLKOUT1/2/3	-	-142	-	dBc/Hz

Additive Phase Noise	APN-2	CLKIN=26MHz and 10 kHz offset CLKOUT1/2/3	-	-156	-	dBc/Hz
Additive Phase Noise	APN-3	CLKIN=26MHz and 100 kHz offset CLKOUT1/2/3	-	-164	-	dBc/Hz
Power-up Time	tPU	Time for CLKOUT1/2/3 frequency to reach valid frequency after power supply reaches 0.9xVDDvalue	-	100	200	ns
Output Enable Time	tOE1	Time from OE raising edge to active at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Disable Time	tOD	Time from OE falling edge to Hi-Z at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Enable Time	tOE2	Active recovery time from standby (CLKIN=0 or 1) to active at outputs CLKOUT1/2/3	-	100	-	ns

DC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 3.3V+/- 10% and Operation Temperature Range -40 to +85°C

Description	Symbol	Condition	Min	Typ	Max	Unit
Operating Voltage	VDD	Operation range , 3.3V+/-10%	2.95	3.3	3.65	V
Operating Temperature	TA	I-Grade	-40	25	85	°C
Input Low Voltage	VIL	CMOS Level, Pins 3.5, 6 and 7	VSS	-	0.3VDD	V
Input High Voltage	VIH	CMOS Level, Pins 3.5, 6 and 7	0.7VDD	-	VDD	V
Output High Voltage	VOH	IOH=-4mA , Pins 4, 8, 9 and 10	VDD-0.4	-	-	V
Output Low Voltage	VOL	IOL=-4mA, Pins 4, 8, 9 and 10	-	-	0.5	V
Input Leakage Current	ILH	VIN=VDD, Pins 5, 6 and 7	-35	-	35	µA
Input Leakage Current	ILL	VIN=GND, Pins 5, 6 and 7	-20	-	20	µA
Pull-Down Resistor	RPD	Pins 5, 6 and 7	100	150	250	kΩ
Operating Supply Current	IDD1	CLKIN=26MHz, OE1=OE2=OE3=1	-	3.4	-	mA
Operating Supply Current	IDD2	OE1=OE2=OE3=0 CLKIN=Low or High	-	-	2.0	µA
Input Capacitance	CIN	Pins 5, 6 and 7	-	3	5	pF
Load Capacitance	CL	CLKOUT1/2/3, Pins 8, 9 and 10	-	10	25	pF

AC Electrical Characteristics (I-Grade)

Unless otherwise stated VDD= 3.3V+/- 10% and Operation Temperature Range -40 to +85°C

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Input Clock Range	CLKIN	External Clock, CMOS square wave	10	26.000	52	MHz
Output Clock Range	CLKOUT	External Clock, CMOS square wave CLKOUT1/2/3	10	26.000	52	MHz
Input Clock Voltage Swing Level	VINpp	VDD=3.3V, connect to CLKIN directly	1.32	1.4	-	V
		VDD=3.3V, connect to CLKIN through AC coupling and bias circuit	0.6	-	-	V
Input Duty Cycle	DCIN	CLKIN, Pin 3	30	50	70	%
Output Clock Rise Time	tr	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	1.2	2.2	ns
Output Clock Fall Time	tf	VDD=1.8, CL=10pF, measured from 10 to 90% of VDD, Pins 4, 8, 9 and 10	-	1.2	2.2	ns
Additive Phase Noise	APN-1	CLKIN=26MHz and 1 kHz offset CLKOUT1/2/3	-	-138	-	dBc/Hz
Additive Phase Noise	APN-2	CLKIN=26MHz and 10 kHz offset CLKOUT1/2/3	-	-157	-	dBc/Hz
Additive Phase Noise	APN-3	CLKIN=26MHz and 100 kHz offset CLKOUT1/2/3	-	-165	-	dBc/Hz
Power-up Time	tPU	Time duration until CLKOUT1/2/3 frequency reaches valid frequency after power supply reaches 0.9xVDD value	-	100	200	ns
Output Enable Time	tOE1	Time from OE raising edge to active at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Disable Time	tOD	Time from OE falling edge to Hi-Z at outputs CLKOUT1/2/3 (Asynchronous)	-	25	-	ns
Output Enable Time	tOE2	Active recovery time from standby (CLKIN=0 or 1) to active at outputs CLKOUT1/2/3	-	100	-	ns

SL18860DC CLKOUT1/2/3							
Phase Noise (dBc/Hz) CL=15pF.							
VDD(V)	100hz	1Khz	10Khz	100Khz	1Mhz	5Mhz	Fig #
1.8	-115.52	-139.85	-150.79	-159.31	-160.52	-162.52	1
2.5	-125.16	-142.67	-156.37	-164.02	-166.45	-167.02	2
3.3	-116.60	-138.06	157.41	-164.88	-167.21	-168.57	3

Table 2. Output Phase Noise Summary Table

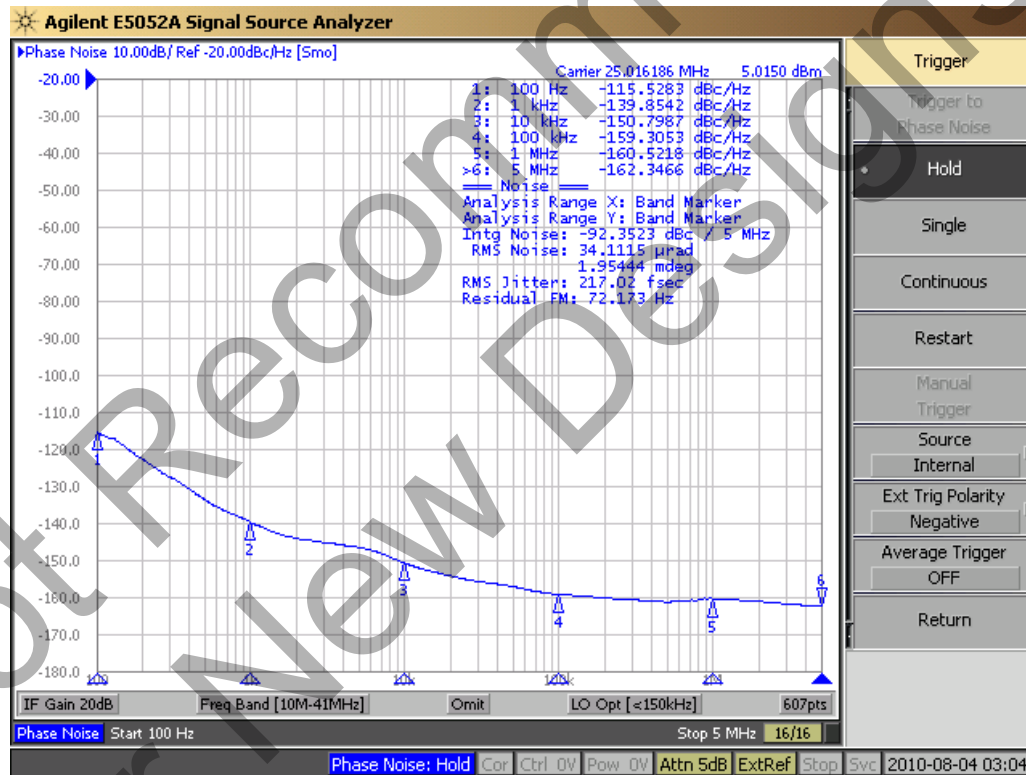


Figure 1. Output Phase Noise VDD=1.8V, CL=15pF

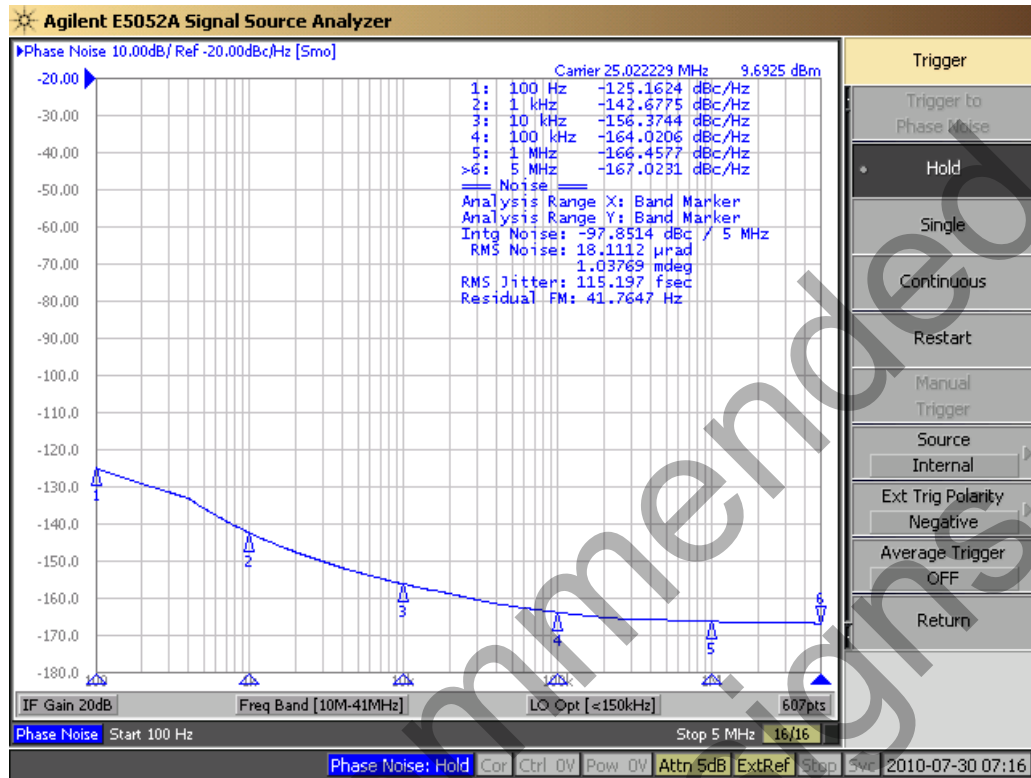


Figure 2. Output Phase Noise VDD=2.5V, CL=15pF

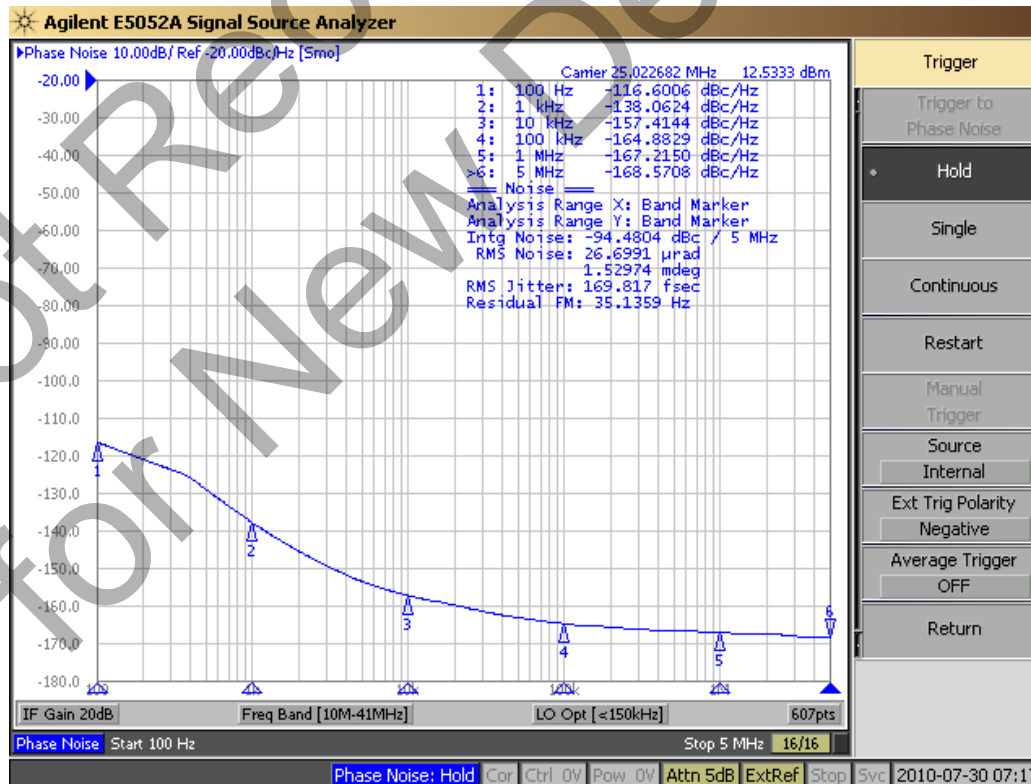
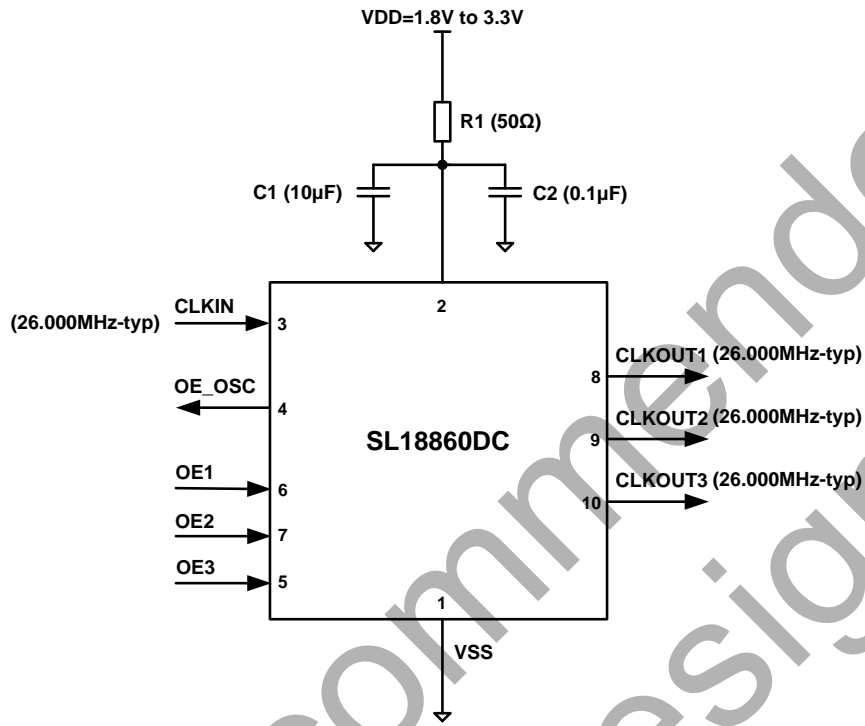
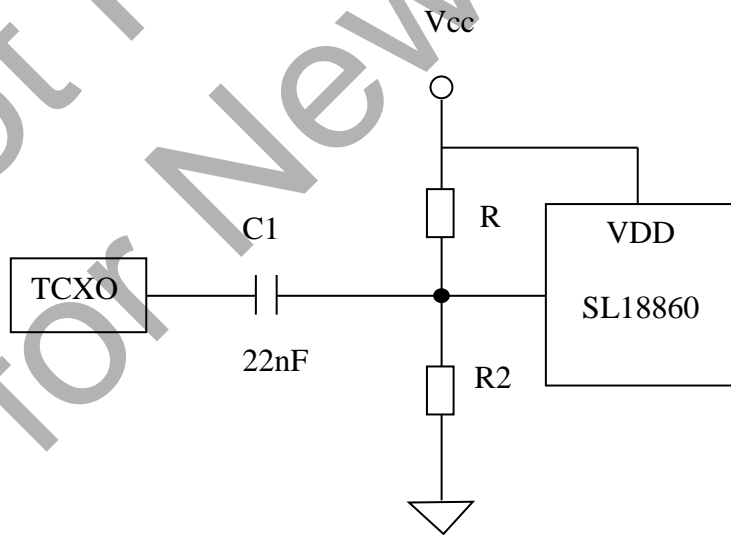


Figure 3. Output Phase Noise VDD=3.3V, CL=15pF

Typical Application Circuit

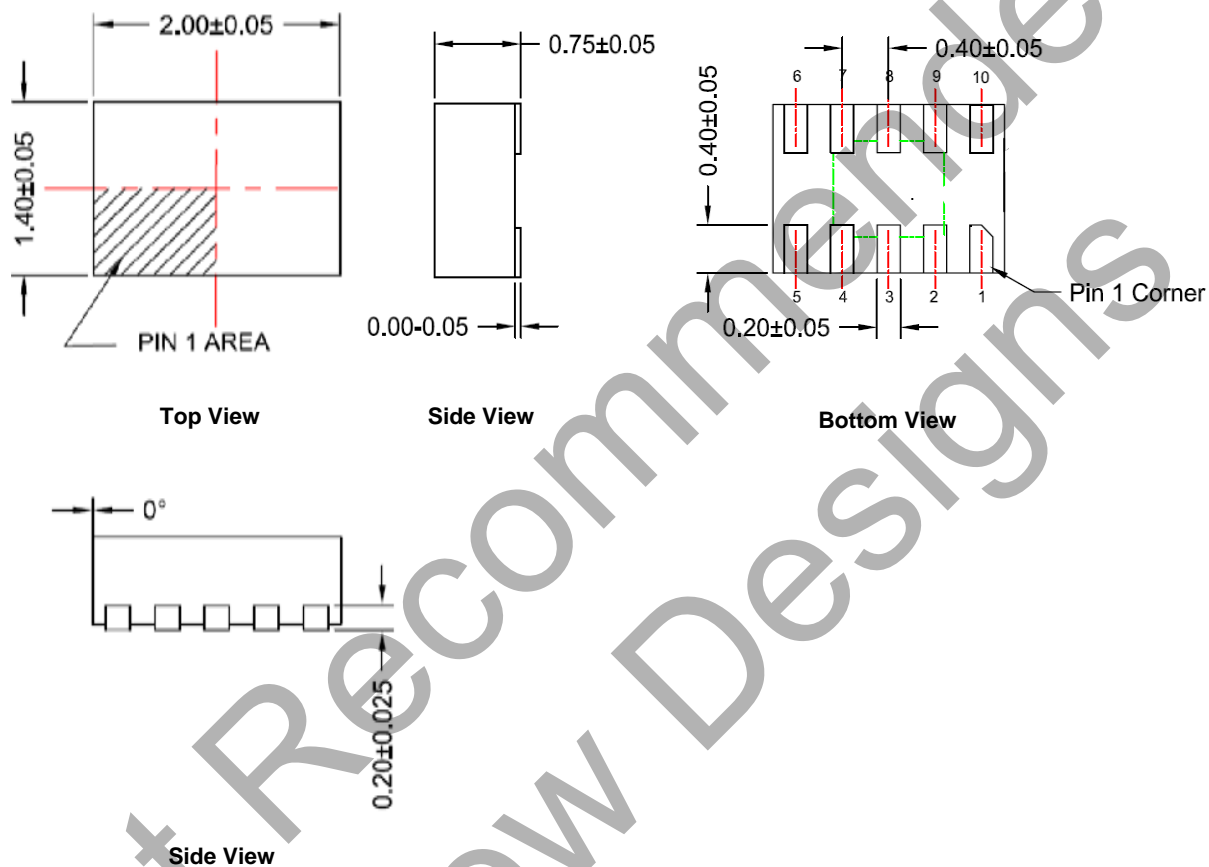


AC coupling and bias circuit



Package Outline and Package Dimensions

10-Pin TDFN Package (1.4x2.0x0.75 mm)



Ordering Information

Ordering Number	Shipping Package	Package	Temperature
SL18860DC	Tube	10-pin TDFN	-40 to 85°C
SL18860DCT	Tape and Reel	10-pin TDFN	-40 to 85°C

Note:

The SL18860 is RoHS compliant



Pin 1

Line	Characters	Description
1	TTTT	Manufacturing Trace Code
2	YWW	Characters corresponding to the last digit of year (Y) and work week (WW) of package assembly



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